Properties of plane and axially ...

S/040/62/026/006/006/015 D234/D308

u being the velocity of sound. If  $(vH)/\rho$  is independent of  $\varkappa$  the integral is

$$P - \frac{v^2}{2} = f_2(z)$$
. (1.19)

If (vH) = 0 and the gas is isentropic both integrals apply. Then, if  $f_1 = 0$  or  $f_2 = 0$ , the quantity  $z = -\rho v_x/\rho v_y$  must satisfy

These results are applied to the radial and vortex flow. For axially symmetrical flows  $\Upsilon$  and  $\kappa$  are defined by

$$\rho \mathbf{v}_{\mathbf{r}} = \frac{1}{\mathbf{r}} \frac{\partial \underline{\mathbf{v}}}{\partial \mathbf{z}}, \quad \rho \mathbf{v}_{\mathbf{z}} = -\frac{1}{\mathbf{r}} \frac{\partial \underline{\mathbf{v}}}{\partial \mathbf{r}}, \quad \mathbf{H}_{\mathbf{r}} = \frac{1}{\mathbf{r}} \frac{\partial \mathbf{z}}{\partial \mathbf{z}}, \quad \mathbf{H}_{\mathbf{z}} = -\frac{1}{\mathbf{r}} \frac{\partial \mathbf{x}}{\partial \mathbf{r}}$$
(5.1)

and introduced as independent variables into the differential equations.

SUBMITTED: July 25, 1962

Card 2/2

1 3107G85 EWI(1		//E4A(3)=2: P3-6/P6-4/Pab-10/P1-4
ACCESSION ER:	AR5004849	B/0058/64/000/011/G004/G004
SOURCE: Ref. :	zh, Pizika, Mbs. 11G30	52 3
Atronom Jonate	ov, Yu. P.,	**************************************
volume Invest	igation of the stabilit	y of a rotating <u>plasma pinch</u>
CIVED SOURCE:	Uch: zap. <u>Orskiy gos</u> .	oed. in-t, vyp. 5, 1963, 38-49
	STANDED SEED OF THE PROPERTY O	pinch rotating plasma
PRANSIALION: VORTICLEY OF E	The stability of an ide he plasma inside the pi	al plasma cylinder is analyzed. nch is assumed.
E BUB CODE: MC	ENCL	i 00 = /
17:		

IADITVAN, K. G.

"Food of the Sevan Trout." Card Piol Sci, Acad Sci Armenian 33E, Yerewal, 1973.
(NZhBiol, No 1, Jan 55)

Survey of Scientific and Technical Dissertations Defended at USSR Higher Educational Institutions (13) SO: Sum. 500, 20 Jul 55

The state of the settle st

5/094/60/000/003/001/003 E073/E335

AUTHOR: Ladilov, V.Ye.

25

TITLE:

On Protecting Cables Laid Underground by means

of Ferroconcrete Slabs

PERIODICAL: Promyshlennaya energetika, 1960, No. 3, p. 25

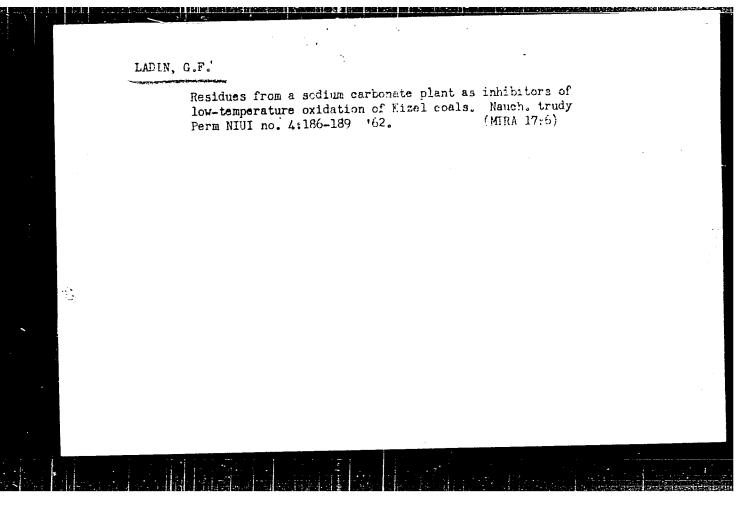
TEXT: In an earlier article Raytsel'skiy and Shteynberg (Ref. 1) aealt with the problem of protecting reliably and economically underground cables by covering them with ferroconcrete slabs instead of using bricks for that purpose. This contravenes the official specifications (II-3-47) which require laying of slabs or bricks transversely to the cable line. Covering of one or two cables laid in the ground with slabs of 150 and 300 mm width respectively does not protect the cables from oblique impacts from a crowbar. It is practically impossible to cover cables with slabs in such a way that the vertical axis of a cable should coincide with the axis of the slabs. Laying of the cable with loops and possible transverse shifts of the cable increase the danger of mechanical damage. The technical and economic data quoted by the authors are not relevant since they Card 1/2

S/094/60/000/003/601/003 E073/E335

On Protecting Cables Laid Underground by means of Ferroconcrete Slabs

compare laying of bricks in the transverse direction with laying of ferroconcrete plates in the longitudinal direction. Under equal conditions laying of 50 mm thick ferroconcrete plates instead of bricks will be considerably more expensive. In view of their higher strength, the author recommends that ferroconcrete plates (30 x 150 x 250 mm) be used and laid transversely to the cable lines. It is pointed out in an editorial note that the merit of the criticised article is the proposal for elaborating a specification on the use of ferroconcrete plates (not of the thickness of 30 mm proposed by the author of this paper) which, owing to their high strength and particularly owing to their shape, will reduce the danger of damaging cables laid underground. There are 2 figures and 1 Soviet reference.

Card 2/2



CHUVIN, V.P.; KULIKOV, O.T., inzh.; LADIN, M.N., inzh.; LATSKIY, V.I., inzh.; ZIMIN, V.A., inzh.; LEVCHENKO, K.P., inzh.; LEVIN, S.S., inzh.; SERGEYEV, V.V., inzh.

\*Ural-61\* boring machine. Gor.zhur. no.2:53-55 F '64. (MIRA 17:4)

1. Glavnyy instruktor Magnitogorskogo zavoda gornogo oborudovaniya (for Chuvin). 2. Nauchno-issledovatel kiy i proyektno-konstruktorskiy institut gornogo i obogatitel nogo oborudovaniya, Sverdlovsk (for Latskiy, Zimin, Levchenko, Levin, Sergeyev).

ABDULIN, A.; ALEKSEYEV, I.; BANTLE, O.; BOBROV, L.; BOZHANOV, B.;

BOYKO, V.; BONDAREV, K.; BORZOV, V.; VERKHOVSKIY, N.; GUBAREV, V.;

GUSHCHEV, S.; DEBABOV, V.; DIKS, R.; DMITRIYEV, A.; ZHIGAREV, A.;

ZEL'DOVICH, Ya.; ZUBKOV, B.; IRININ, A.; IORDANSKIY, A.;

KITAYGORODSKIY, P.; KLYUYEV, Ye.; KLYACHKO, V.; KOVALEVSKIY, V.;

KNORRE, Ye.; KONSTANTINOVSKIY, M.; LADIN, V.; LITVIN\_SEDOY, M.;

MALEVANCHIK, B.; MANICHEV, G.; MEDVEDEV, Yu.; MEL'NIKOV, I.;

MUSLIN, Ye.; NATARIUS Ya.; NEYFAKH, A.; NIKOLAYEV, G.; NOVOMEYSKIY, A.;

OL'SHANSKIY, N.; OS'MIN, S.; PODOL'NYY, R.; RAKHMANOV, N.; REPIN. L.;

RESHETOV, Yu.; RYBCHINSKIY, Yu.; SVOREN', R.; SIFOROV, V.; SOKOL'SKIY, A.;

SPITSYN, V.; TEREKHOV, V.; TEPLOV, L.; KHAR'KOVSKIY, A.; CHERNYAYEV, I.;

SHAROL', L.; SHIBANOV, A.; SHIBNEV, V.; SHUYKIN, N.; SHCHUKIN, O.;

EL'SHANSKIY, I.; YUR'YEV, A.; IVANOV, N.; LIVANOV, A.; FEDCHENKO, V.;

DANIN, D., red.

[Eureka] Evrika. Moskva, Molodaia gvardiia, 1964. 278 p. (MIRA 18:3)

C L 21794-66 SOURCE CODE: UR/0286/65/000/024/0083/0083 ACC NR: AP6002922 AUTHORS: Naumenko-Bondarenko, I. I.; Gorin, V. P.; Usacheva, A. H.; Stepin, H. D.; Yurkovetskiy, S. G.; Aksenov, M. Z.; Yefremov, V. V.; Kolentsev, A. H.; Baryshev, Yu. M.; Lad'ina, V. M.; Fel'dman, Yu. S. ORG: none TITLE: A ground gravimeter Class 42, No. 177106 SOURCE: Byulleten' izobreteniy i tovarnykh znakov, no. 24, 1965, 83 TOPIC TAGS: gravimetric analysis, measuring instrument, measurement accuracy ABSTRACT: This Author Certificate presents a ground gravimeter containing a quartz elastic sensitive system, units of distance control and control of the rotation angle of a micrometric screw, and an assembly of a photoelectric device with an illuminator. The design increases the precision of the measurements and makes possible the determination of the errors of the distance transmission. The unit of distance control in the gravimeter has precision multiple-turn linear potentiometers interconnected in a bridge circuit. One of the potentiometers is mounted in the gravimeter and the other on a control panel. The rotors of these potentiometers are connected with a tachometer. To reduce the temperature effects on the quarts sensitive system, the latter system is insulated from the photoelectric device. Z SUB CODE: OS/ SUBM DATE: 21Jan64 550.831 UDC: Cord 1/1 1X

### LADINSKAYA, M.Yu.

Effect of some phenothiazine derivatives on mardiac reflexes [with summary in English]. Biul.eksp.biol. 1 med. 44 no.12:77-81 D '57.

(MIRA 11:4)

1. Iz laboratorii chastnoy farmakologii (zav. - deystvitel'nyy chlen AMN SSSR prof. V.V.Zakusov) Instituta farmakologii i khimioterapii dir. - deystvitel'nyy chlen AMN SSSR V.V.Zakusov) AMN SSR, Moskva.

(Predstavlena deystvitel'nym chlenom AMN SSSR V.V.Zakusovym.

(PHENOTHIAZINE, related cpds.

10-(N-p-methylpiperazinylethyl)phenothiazine, eff. on heart (Rus))

(CHLERPROMAZINE, effects, on heart (Rus))

(HEART, effect of drugs on, 10-(N-p-methylpiperazinylethyl)phenothiazine & chlorpromazine (Rus))

LADINSKAYA, M. Yu., Candidate of Med Sci (diss) -- "The effect of certain pharmacological substances on cardiac reflexes". Moscow, 1959. 11 pp (Acad Med Sci USSR), 200 copies (KL, No 20, 1959, 115)

# IADINSKAYA, N.Yu. Effect of certain analgesics and novocaine on reflexes originating in the heart. Farm. i toks. 22 no.2:104-109 Mr-Ap '59. (MIRA 12:6) 1. Leboratoriya chastnoy farmakologii (zav. - deystvitel'myy chlen AMM SSSR prof. V.V. Zakusov) Instituta farmakologii i khimioterapii AMN SSSR. (CORONARY VESSELS, eff. of drugs on, analgesics & procaine, on reflex action in cats (Rus)) (ANALESICS AND ANTPTRETICS, eff. on coronary reflex action in cats (Rus)) (PROCAINE, eff. same)

### LADINSKAYA, M.Yu.

Effect of some analgesic substances and novocaine on reflexes from the heart. Uch.zap.Inst.farm.i khimioter.AMN SSSR no.2: 105-113 '60. (MIRA 15:10)

1. Laboratoriya chastnoy farmakologii (zav. - deystvitel'nyy chlen AMN SSSR prof. V.V.Zakusov).

(ANALGESICS) (NOVOCAINE)

(HEART) (REFLEXES)

L 5256**-**66

ACC NR: AP5027479

SOURCE CODE:

UR/0219/65/060/010/0065/0068

AUTHOR: Rudakova, I. S.; Ladinskaya, M.

ORG: Department of Chemotherapy, Institute of Pharmacology and Chemotherapy AMN SSSR, Moscow (Otdel khimioterapii, Institut farmakologii i khimioterapii AMN SSSR)

TITLE: Action mechanism of some esculetin derivatives

SOURCE: Byulleten! eksperimental!noy biologii i meditsiny, v. 60, no. 10, 1965, 65-68

TOPIC TAGS: reaction mechanism, vitamin, experiment animal, biologic metabolism, blood, coagulation

ABSTRACT: Based on earlier studies involving the vitamin P effect of nitrogen-containing derivatives of 4-methylesculetin on healthy and irradiated animals, the effect of esculamine (8-dioxydiethylaminomethyl 4-methylesculetin HCl) and 8-dimethylaminomethyl-4-methylesculetin HCl (#33-0-45) on the activity of epinephrine, acetylcholine, hyaluronidase, histamine and the blood prothrombin time was studied. Acute tests were conducted on anesthesized cats to determine blood pressure and respiration rate after administration of epinephrine and acetylcholine under the influence of the esculetins. Antihyaluronidase activity was

Card 1/2

VDC: 612.015.643+615.32:577.164.3-092.259

L 5256-66

ACC NR. AP5027479

determined by measuring the lesser spread of subcutaneous trypan blue in rabbits, antihistamine was measured by the opthalmic reaction in the guinea pig, and prothrombin time was measured in rabbits. Esculamine proved to be the more active preparation. Intravenous administration of the two esculetin derivatives by themselves increased blood pressure, but had no effect on epinephrine and acetylcholine. Their antihyaluronidase activity was most pronounced after 30 min and disappeared after one hr. Some antihistamine effect was seen, particularly after 3 hrs. Prothrombin time increased after 3 x 1 daily subcutaneous injections of 50 mg/kg esculamin both in healthy and irradiated (800 r) rabbits; the index rose to 128% in healthy animals, stayed at 109-100% in the irradiated animals, and dropped to 81% in controls. It is concluded that N-containing derivatives of 4-methylesculetin possess antihyaluronidase activity and a certain antihistaminic effect, and improve blood coagulability; these properties may be important for the mechanism of the vitamin P effect. Orig. art. has: 3 tables and 2 figures.

CHANGE LEGISLAND CHANGE CHANGE CONTRACTOR OF THE PARTY OF

SUB CODE: LS,OC, GC/ SUBM DATE: 13Apr64/ ORIG REF: 006/ OTH REF: 000

(Card 2/2

LADINSKIY, A. S.

Buildings, Prefabricated

Demountable small houses. Reviewed by N. S. Lutov, Stroi. prom., 30, No. 2, 1952.

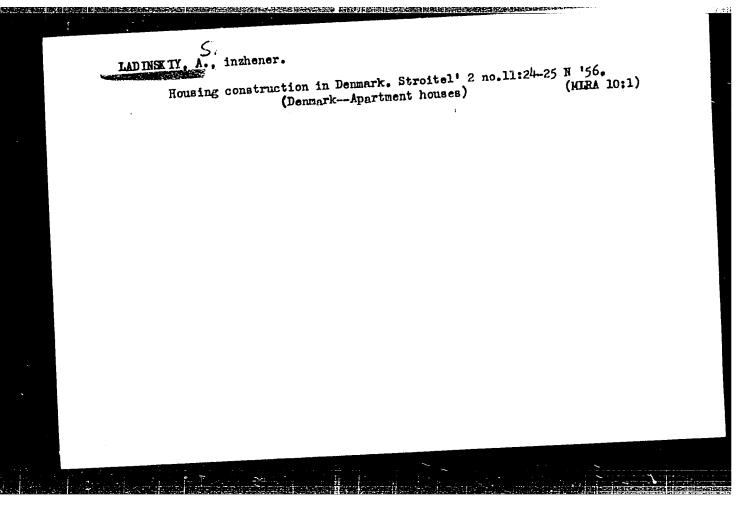
Monthly List of Russian Accessions, Library of Congress, March 1952. Unclassified.

**体验的,我们就是一个人的人,我们就是一个人的人的人,我们就是一个人的人的人的人的人的人的人,我们就是一个人的人的人的人的人的人的人的人的人的人的人的人的人的人的人的人的人** 

ZHUKOV, D.V., kandidat tekhnicheskikh nauk; IADINSKIY, A.S., inzhener, laureat Stalinskoy premii.

[Drying plaster and stone walls of buildings] Sushka shtukaturki i kamennykh sten zdanii. Moskva, Gos.izd-vo lit-ry po stroitel'stvu i arkhitekture, 1953. (MLRA 6:8) 61 p. (Building)

Reinforced concrete construction plants are the basis of industrial construction. Biul.stroi.tekh. 10 no.11:1-3 Je '53. (MLRA 6:8) struction. Biul.stroi.tekh. (Reinforced concrete construction)



SCURCE CCDE: UR/0030/66/000/006/0033/0041 L 44808-66 AUTHOR: Ladinskiy, A. S. (Chief engineer)

ORG: Administration of Capital Construction, Siberian Department, AN SSSR (Upravleniye kapital nogo stroitelystva Sibirskogo otdeleniya AN SSSR)

TITLE: Science city being built near Novosibirsk (USSR)

SOURCE: AN SSSR. Vestnik, no. 6, 1966, 33-41

MONTO MASS: Topport Special Property Sibirskogo otdeleniya and SSSR. ACC NR: AP6029218 TOPIC TAGS: research facility, city planning, city construction, academic institution ABSTRACT: The headquarters of the Siberian Division of the USSR Academy of Sciences near Novosibirsk has been under construction since 1961. In addition to the 16 institutes of the Academy of Sciences which are conducting research here, there are also the Novosibirsk University and a special physicomathematical boarding school. The city, which already has a population of 30,000, represents a challenging experiment for Soviet city planners and builders. It embodies a new design and development concept and is considered the prototype for new cities in Siberia. It is in this context that the design and location of research, modeling, manufacturing, educational, service, and other facilities in the science city are discussed. The science center has a total of 120,000  $\mathrm{m}^2$  of working area built at a cost of 91,300,000 rubles. The residential part of the city has 300,000  $\mathrm{m}^2$  of living area constructed at a cost of 87.9 million rubles. The city's site is located near Lake Ob' 25-30 km from Novosibirsk, a large industrial and cultural center. With a careful selection of individual building sites, and the use of natural clearings whenever possible, it has been necessary to clear only 120 ha of land. The city is built in two sections, one residential and the other containing the IDC: 001.89 Card 1/3

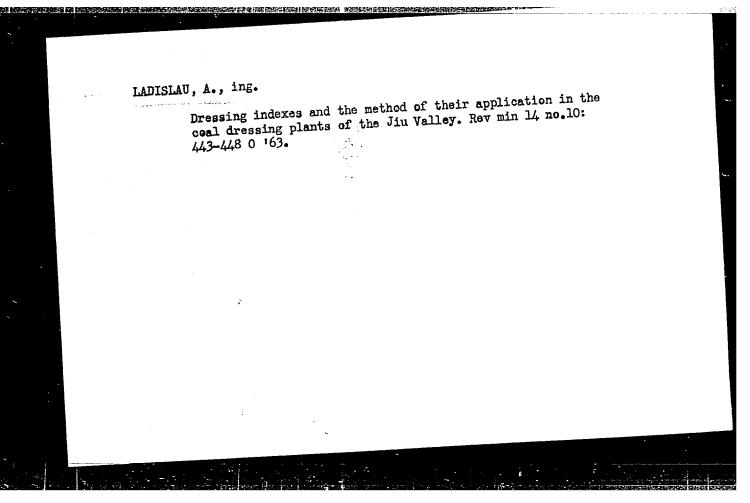
1, 44808-66 university, research institutes and laboratories, etc., and these are ACC NR: AP6029218 separated by a strip of trees. Practically every institute has its own laboratory, one or more workshops, and a modeling facility, in addition to the main building for theoretical studies. Buildings throughout the area are of two standard designs and combinations thereof. One design, used for theoreticalstudies buildings, has 13- and  $20-m^2$  rooms and is generally less expensive to build. Another design, a three-story building with a central co.cidor plan, has ventilation, numerous outlets for electricity, gas, etc., and is specially designed for laboratories. Almost all institutes have their own workshops located in fairly large structures and operated by large staffs. Finally, the city has huge structures erected for housing various equipment for modeling processes on a large scale. The following institutes are specifically mentioned: Institute of Hydrodynamics; Institute of Nucelar Physics; Institute of Catalysis; Institute of Organic Chemistry; Institute of Inorganic Chemistry; Institute of Theoretical and Applied Mechanics; Institute of Chemical Kinetics and Combustion; Institute of Since the computer is rapidly becoming an indispensable tool of all Physics of Semiconductors. sciences, a large computing center was built having about 100,000 m2 of space; it is in the process of getting a new high-speed computer. Other facilities include an experimental plant in whose shops laboratory equipment for a number of institutes is built, and which serves as an auxiliary industrial base for the city together with the workshops of the Card 2/3

SUB CODE: 05/ SUBM DATE: none	

KRAMARENKO, G.N.; NECHAYEVA, Z.P.; TKACHENKO, S.S., dotsent; FLORENSOV, A.A., kand.med.nauk; LADIS, I.A.; VARFOLOMEYEVA, S.N.; KOSTRIKOV, V.S., kand.med.nauk

Reports on meetings of societies of traumatologists and orthopedists. Ortop., travm. i protez. 21 no.8:82-94 Ag '60. (MIRA 13:11)

(ORTHOPEDIC SOCIETIES)



L 38331-66 EWT(d) IJP(c)  SOURCE CODE: CZ/0045/66/000/001/0053/0057  ACC NR: AP6027997  AUTHOR: Drs, Ladislav (Praguo)  ORG: Department of Descriptive Geometry, Mechanical Engineering Faculty, Czech  ORG: Technology, Prague (Katedra deskriptivni geometrie, Strojna Fakulta,	
ORG: Department of Descriptive Geometry, Mechanical Engineering Faculty, Institute of Technology, Prague (Katedra deskriptivni geometrie, Strojna Fakulta, Ceske vysoke uceni technicke)  TITIE: Conjugate parallel projections	
SOURCE: Matematicko-fyzikalny casopis, no. 1, 1966, 55-77  SOURCE: Matematicko-fyzikalny casopis, no. 1, 1966, 55-77  morro TAGS: graphic technique, construction, projective geometry	
TOPIC TAGS: graphic technique, construction of the parallel projection U <sub>02</sub> , U <sub>2</sub> ABSTRACT: The article presents the construction of the parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding of the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding of the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding of the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding of the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding of the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding of the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding of the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding of the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding of the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding of the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding of the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding to the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding to the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding to the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding to the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding to the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding to the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding to the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding to the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding to the figure U, using the given parallel projections U <sub>01</sub> and U <sub>1</sub> . Both corresponding to the given parallel projection U <sub>1</sub> and U <sub>1</sub> and U <sub>2</sub> and U <sub>1</sub> and U <sub></sub>	
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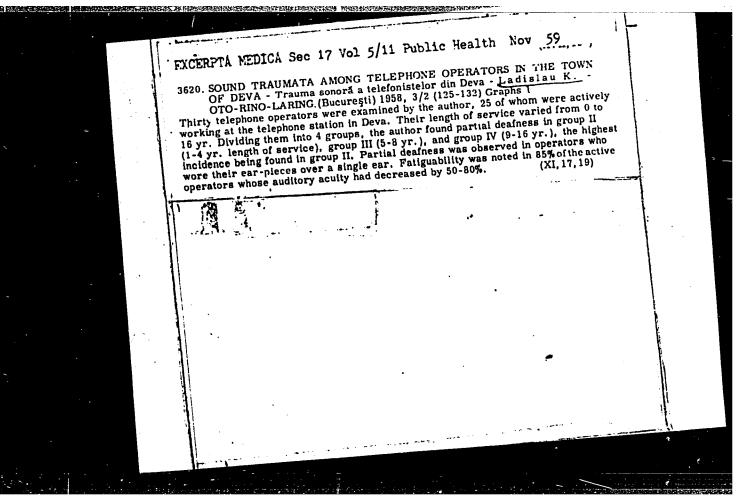
CZECHOSLOVAKIA

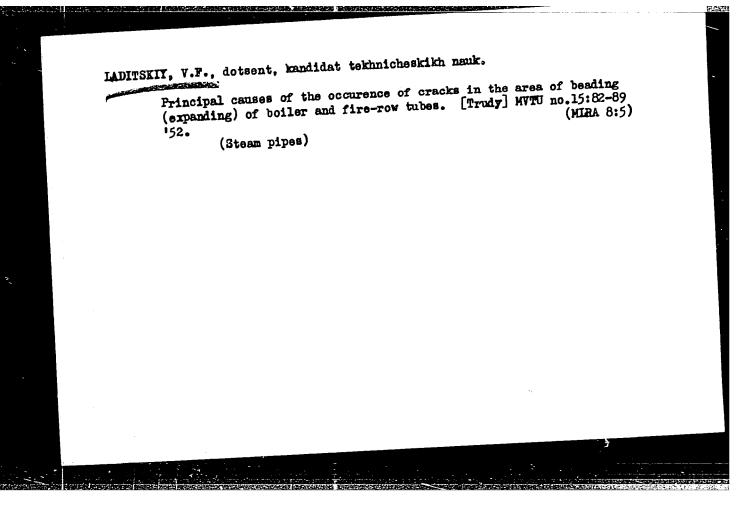
### LADISLAV, B.

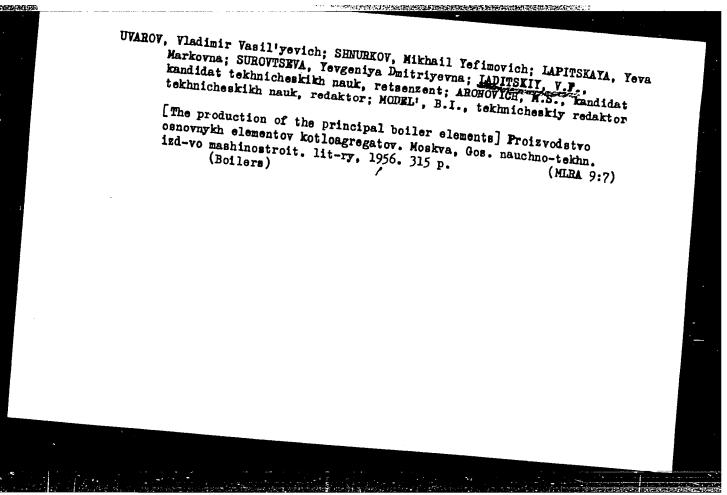
1. Surgical Ward OUNZ N. Jicin (Chirurgicke oddeleni OUNZ N. Jicin); 2. Internal Medicine Ward OUNZ N. Jicin (Vnitrni oddeleni OUNZ N. Jicin); 3. X-Ray Ward OUNZ (Vnitrni oddeleni OUNZ N. Jicin); 4. Oncological N. Jicin (Rtg oddeleni OUNZ N. Jicin); 4. Oncological Ward KNSP Paskov (Onkologicke oddeleni KNSP Paskov)

Prague, Vnitrni lekarstvi, No 11, 1963, pp 1125-1126

"A Case of Extra-Skeletal Myeloma."







SMIRNOV, Vladimir Petrovich. Prinimali uchastiye: IADITSKIY, V.F. kand.tekhn.nauk; SHAPKIN, I.F., kand.tekhn.nauk; MIKHAYLOVICH, A.M., inzh.. KNORRE, G.F., prof., doktor tekhn.nauk, zasluzhennyy deyatel nauki i tekhniki, red.; VORONIN, K.P., tekhn.red.

[Boiler units] Kotel'nye ustanovki. Pod red. G.F.Knorre.

(MIRA 12:8)

Moskva, Gos.energ.izd-vo, 1959. 303 p.

(Boilers)

BOBROVSKIY, Grigoriy Stepanovich; LADITSKIY, V.F., kand. tekhn.
nauk, retsenzent; VOSKRESENSKIY, N.N., inzh., red.;
BASENTSYAN, A.A., inzh., red. izd-va; CHERNOVA, Z.I., tekhn. red.

[Low capacity boiler systems; industrial, municipal and agricultural] Kotel'nye ustanovki maloi moshchnosti; promyshlennye, kommunal'nye i sel'skokhoziaistvennye. Moskva, Gos.
nye, kommunal'nye i sel'skokhoziaistvennye. Moskva, Gos.
nauchno-tekhn. izd-vo mashinostroit. lit-ry, 1961. 311 p.
(MIRA 15:3)

(Boilers)

CIA-RDP86-00513R000928420001-5" APPROVED FOR RELEASE: 06/19/2000

LADIYEV, R. Ya. Dissertation: "Investigation of Heat Transfer to a Boiling Solution of Ammonium Nitrate in Circuits With Artificial and Natural Circulation." Cand Tech Sci, Kiev Polytechnic Inst, Kiev, 1953. Referativnyy Zhurnal--Khimiya, Moscow, No 14, Jul 54.

SO: SUM No. 356, 25 Jan 1955

CIA-RDP86-00513R000928420001-5 Redaktor; GOLOVCHENKO, G., tekhnicheskiy OROSHEV. H.V.; LADIYAV, R. redaktor [Principles of calculations for industrial furnaces; gas machanics and the theory of similitudes ] Osnovy rascheta promyshlennykh pechei; mekhanika gazov i teorii podobiia. Kiev, Gos. izd-vo tekhn. lit-ry (MIRA 8:4) USSR, 1954. 198 p. (Furnaces-Construction) (Dimensional analyses) (Gases, Kinetic theory of)

CIA-RDP86-00513R000928420001-5" APPROVED FOR RELEASE: 06/19/2000

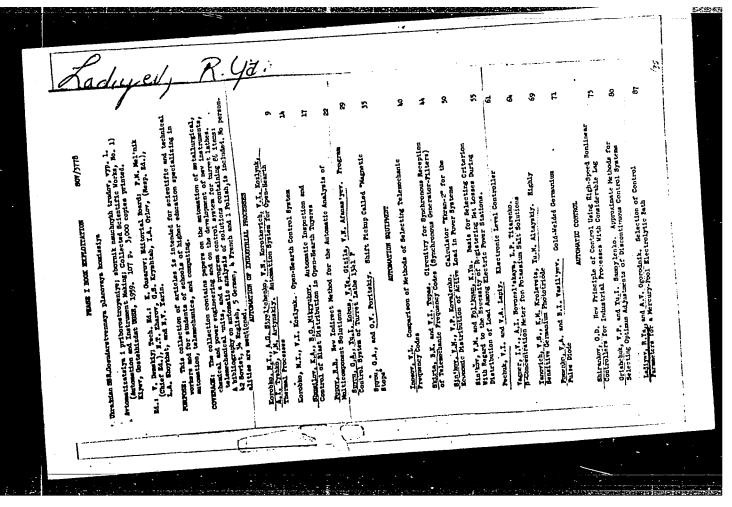
LADIYEV, R. Ya. (Cand. Tech. Sci.)

"The Use of Approximate Thermo-dynamic similarity to Establish Heat Transfer  $R_{\theta}$ lationships during Boiling."

report presented at sci and tech session on Heat Exchange during Change of Aggregate State of Matter (by Comm. on High Steam Conditions, Power Inst. AS USSR, and Inst. Thermal Engineering, AS UkrSSR) Kiev, 23-28 Sep 57.

Kiev Polytech Inst.

"APPROVED FOR RELEASE: 06/19/2000 CIA-RDP86-00513R000928420001-5



CHERNOBYL'SKIY, Iosif Il'ich, prof., doktor tekhn.nauk; BONDAR', Alla Grigor'yevna, dotsent, kand.tekhn.nauk; GAYEVSKIY, Boris Antonovich, dotsent, kand.tekhn.nauk; GORODINSKAYA, Sarra Abramovna, dotsent, kand.tekhn.nauk; LADIYEV, Rostislav Yakovlevich, kand.tekhn.nauk; TANANAYKO, Yuriy Martir'yevich, kand.tekhn.nauk; MIRGORODSKIY, Vasiliy Timofeyevich, insh.; STABNIKOV, V.N., prof., doktor tekhn.nauk, retsenzent; FURER, P.Ya., red.

[Machinery and equipment of chemical industries; principles of theory and design] Mashiny i apparaty khimicheskikh proizvodstv; theory and design] Mashiny i apparaty khimicheskikh proizvodstv; theory and design] Mashiny i apparaty khimicheskikh proizvodstv; osnovy teorii i rascheta. Pod red. I.I.Chernobyl'skogo. Moskva, osnovy teorii i rascheta.

(Chemical industries-Equipment and supplies)

IADIYEV, R.Ya.; OGORODNIK, A.V.

Selecting parameters for the regulation of an electrolytic cell

vith a mercury-pool cathode. Avtom.i prib. no.1:87-91. '59.

(Klectrolysis) (Electrodes, Mercury) (Automatic control)

AKUTIN, G.K. [Akutin, H.K.]; GAYEVENKO, Yu.O. [Haievenko, IU.O.];

DYACHERCO, M.Za.; ZHAROV, M.Z.; IVANOV, S.K.; KARRIUSHIR,

L.B.; KLOUSINSKIY, I.I. [Kodnyts'kyi, I.I.]; KORUS,

[KADUS, IU.I.]; KORCEKO, Y.Y. [Kosliuk, V.I.]; KORYFNIKOV,

P.; KORCEKO, M.I.; KOSTOGRIZOV, V.S. [Zagtchyzov, V.S.];

V.P.; KORCEKO, M.I.; KOSTOGRIZOV, V.S. [Zagtchyzov, V.S.];

LADIINV, R.Za. [Ladiev, R.IA.]; MARTHROM, G.Z. [Maryalik,

LALININ, P.M.; kand.tekhn.nauk; HAVOL'HEV, S.Ya.

[Eavol'niev, S.IA.]; SIN'KOV, V.N.; SPINU, G.O. [Syruu, H.O.];

SHOWRHER, L.A.; SHUMILOV, K.A.; KORSAK Yu.Ye. [Korsak, IU.IS.],

SHOWRHER, I.A.; SHUMILOV, K.A.; KORSAK Yu.Ye. [Korsak, IU.IS.],

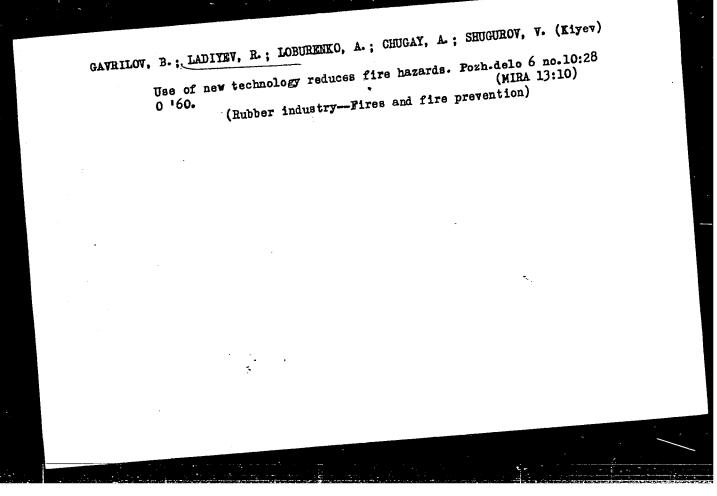
SHOWRHER, I.A. [Lahutin, I.A.], tekhn.red.

[Automation in industry] Avtomatizatsiia v promyslovosti.

Kylv, Derzh.vyd-vo tekhn.lit-ry URSR, 1960. 288 p.

(MIRA 14:12)

(Automation) (Industrial management)



5/123/61/000/004/027/027 A004/A104

AUTHOR:

Ladiyev, R. Ya.

TITLE:

Comparative investigation of the heat transfer to boiling  $\mathrm{NH_{4}NO_{3}}$ solutions in vertical circuits with artificial or natural circulation

so

PERIODICAL:

Referativnyy zhurmal, Mashinostroyeniye, no. 4, 1961, 5, abstract 4Kh39. ("Izv. Kiyevsk. politekhn. in-ta," 1960, v. 30, 120-133)

The author reports on investigations of the heat transfer during the forced motion of the boiling liquid with the purpose of an expedient industrial utilization of evaporation apparatus with artificial circulation. The investigations were carried out at the Laboratory of Machines and Apparatus of Chemical TEXT: Production of the Kiyevskiy ordena Lenina politekhnicheskiy institut (Kiyev "Order of Lenin" Politechnic Institute) based on comparative (on the same boiling pipe) investigations to determine the coefficient of heat transfer in circuits with artificial and natural circulation of the aqueous NH4NO3 solution. There are 5 figures and 3 references.

[Abstractor's note: Complete translation]

Card 1/1

**APPROVED FOR RELEASE: 06/19/2000** 

CIA-RDP86-00513R000928420001-5"

20188

5/196/61/000/001/001/006 E073/E535

11.9400

» سره حرب <sup>بر</sup>

Ladiyev, R. Ya. AUTHOR:

TITLE:

Application of Approximate Thermodynamic Analogy for Establishing the Relations Governing Heat Release

PERIODICAL: Referativnyy zhurnal, Elektrotekhnika i energetika, 1961, No.1, p.4, abstract No.1G22. Izv. Kiyevsk.

politekhn. in-ta, 1960, 30, 175-187

In evaluating experimental data on the coefficient of heat release during boiling of large volumes of liquid with natural circulation, numerous authors use the following dependence

on the heat flux (q):  $\alpha_2 = A_2 q^n$ 

 $A_2$  - function of the physical properties of the liquid depending on pressure. Calculation of A2 is complicated due to the fact that for each pressure the values of a number of physical constants are required which are frequently unknown. By analysing the differential equation of the process the author derives a criterial relation into which the pressure function  $f(p/p_{cr})$  is Card 1/3

CIA-RDP86-00513R000928420001-5" APPROVED FOR RELEASE: 06/19/2000

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Application of Approximate ...

s/196/61/000/001/001/006 E073/E535

introduced, where p is the critical pressure for the given substance. By writing the criterial equation for two pressures (one of which is the atmospheric pressure) and dividing one by the other, the author obtains the dependence f(p/p) in an explicit form. The calculation formulae for the heat release coefficient is given as follows (whereby the symbols have their usual section) is given as follows (whereby the symbols have their usual meanings):

 $\alpha_2 = A_2 \frac{\gamma - \gamma''}{\sigma} q^{0.6} = A_2 \frac{0.6}{\sigma^2} \text{ kcal/m}^2 \cdot \text{hour} \cdot {}^{\circ}\text{C}$ 

where

 $A_2 = 1.69 \frac{\lambda_1}{\gamma_1} \left( \frac{\gamma_1''}{r_1 \gamma_1 \delta_1^2} \right)^{0.6}$ 

A2 does not depend on pressure; the index 1 indicates that the values refer to atmospheric pressure. The following is given in values relet to atmospheric pressure. The rottowing is given in the paper: a comparison of the obtained relation with experimental

Card 2/3

CIA-RDP86-00513R000928420001-5" APPROVED FOR RELEASE: 06/19/2000

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Application of Approximate ...

S/196/61/000/001/001/006 E073/E535

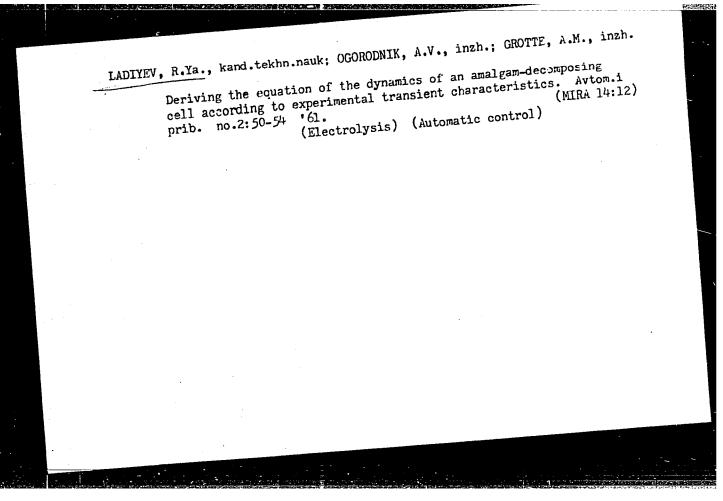
data and values of  $A_2 \cdot 10^6$  for water, ethyl alcohol, heptane, pentane, benzol, respectively, for the power index n equalling 0.6-66; 17.3, 15.2, 11.2, 10.5 and for n equalling 0.7-21: 5.5, 4.6, 3.2, 3.1. It is shown that reliable extension of the obtained criterial relation to other liquids, and in the first instance to strongly associated liquids, depends on whether at the saturation line these substances comply with the law of the states on which the study made in the paper is based. 14 bibliographic references.

Note: The above text is a full translation of the original Soviet abstract.

Card 3/3

CHERNOBYL'SKIY, Iosif Il'ich, doktor tekhn. nauk, prof.; BONDAR', Alla Grigor'yevna, kand. tekhn. nauk, dots.; GAYEVSKIY, Boris Antonovich, kand. tekhn. nauk, dots.; GORODINSKAYA, Sara Abramovna, vich, kand. tekhn. nauk, dots.; LADIYEV, Rostislav Yakovlevich, kand. kand. tekhn. nauk, dots.; tekhn. nauk; TANANAYKO, Yuriy Martir'yevich, kand. tekhn. nauk, dots.; MIRGORODSKIY, Vasiliy Timofeyevich, inzh.; rurer, P.Ya., red.; GORNOSTAYPOL'SKAYA, M.S., tekhn. red.

[Machinery and apparatus for the chemical industries; principles of theory and design] Mashiny i apparaty khimicheskikh proizvodst; ostheory apparaty khim



CHERNOBYL'SKIY, Iosif Il'ich, doktor tekhm. nauk, prof.; EONDAR',
CHERNOBYL'SKIY, losif Il'ich, doktor tekhm. nauk, dots.; GAYEVSKIY,
Boris Antonovich, kand. tekhm. nauk, dots.; GNATOVSKIY,
Boris Antonovich, kand. tekhm. nauk, dots.; MEDINSKAYA,
Vesilty. Ivanovich, kand. tekhm. nauk, dots.; MEDINSKAYA,
Vesilty. Rostislav

Sara Abramovna, kand. tekhm. nauk, dots.; MINDORDSKIY, Vasiliy Timofeyevich,
SORDKA, M.S., red.; GORNOSTAYPOL'SKAYA, M.S., tekhm. red.
SORDKA, M.S., red.; GORNOSTAYPOL'SKAYA, M.S., tekhm. red.

[Machinery and apparatus of the chemical industry]Mashiny i apparaty khimicheskoi promyshlennosti. Pod red. I.I.Chernob yl'paraty khimicheskoi promyshlennosti. Pod red. I.I.Chernob yl'skogo. Moskva, Mashglz, 1962. 521 p.
(Chemical engineering—Equipment and supplies)

LADIYEV, R.Ya.; GAVRILOV, B.M.; SHUGUROV, V.S.; LOBURENKO, A.I.

Automation of the operations of the benzene retrieving system.

(MIRA 16:5)

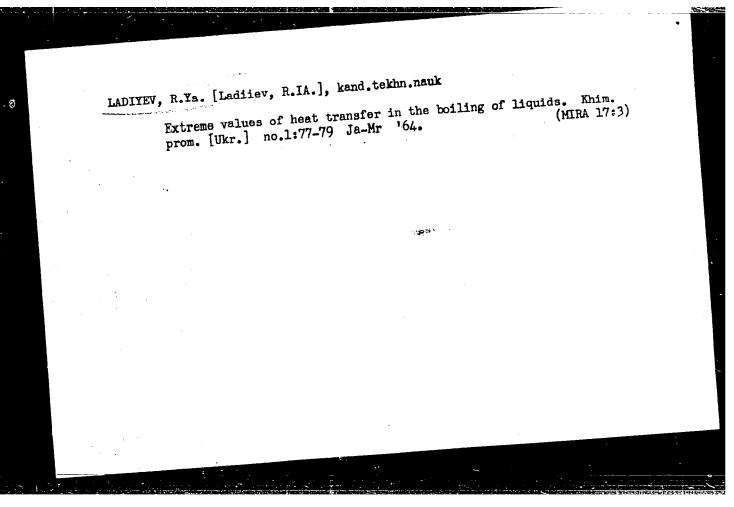
Kauçk, i rez. 21 no.8:45-47 Ag !62.

1. Institut avtomatiki Gosplana UkrSSR.

(Rubber industry—Equipment and supplies)

(Automatic control)

(Benzene)



LADIYEV, R.Ya. [Ladiiev, R.IA.], kand. tekhn. nauk; GOVDYA, Yu.D. [Hovdia, IU.D.]

Automatic control of the concentration of sulfuric acid in turbulent absorbers. Khim. prom. [Ukr.] no.3:53-56 Jl-S '64.

(MIRA 17:12)

Calculating the temperature field in a vapor-liquid heat exchanger taking the variable properties of the heated exchanger taking the variable properties of the heated exchange the temperature field in a vapor-liquid heat liquid into account. Khim. mashinostr. no.1:115-119 '165.

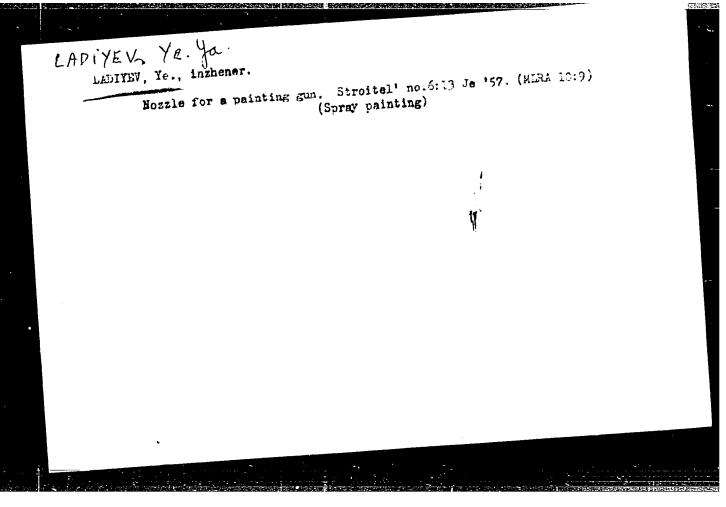
Dynamic characteristics of a vapor-liquid heat exchange taking the changes in liquid parameters into accour. MIRA 18:9)

CHUGAY, A.D.; LADIYEV, R. Ya.; GAVRILOV, B.M.; LOBURENKO, A.I.; SHUCUROV, V.S.

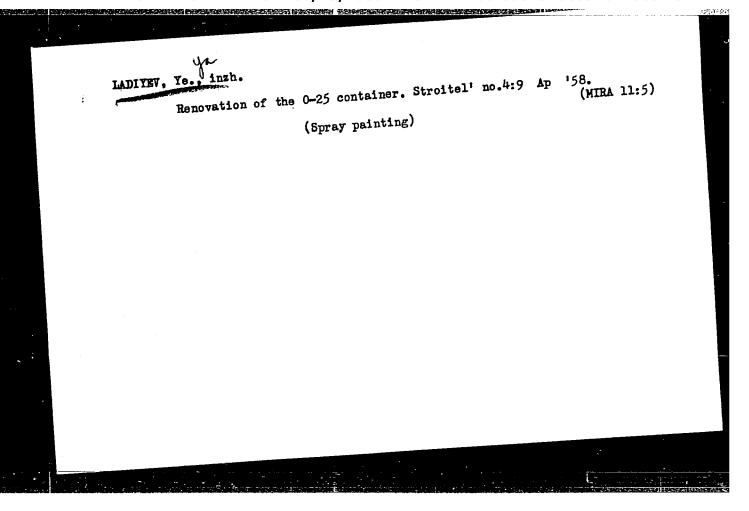
Processes for the manufacture of rubber adhesives and their automatic (MIRA 14:6)

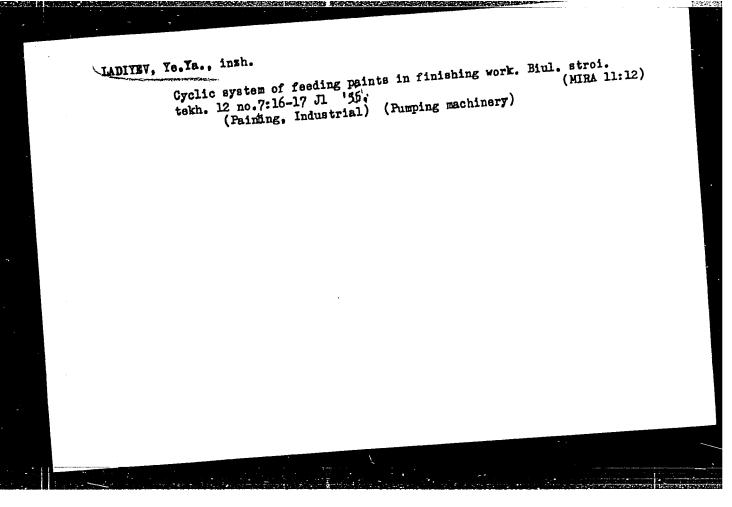
1. Kiyevskiy zavod "Krasnyy rezinshchik" i Institut avtomatiki

(Rubber)
(Adhesives)
(Automatic control)



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LADIYEV, Ye.Ya.,

IADIYEV, Ye.Ya.,

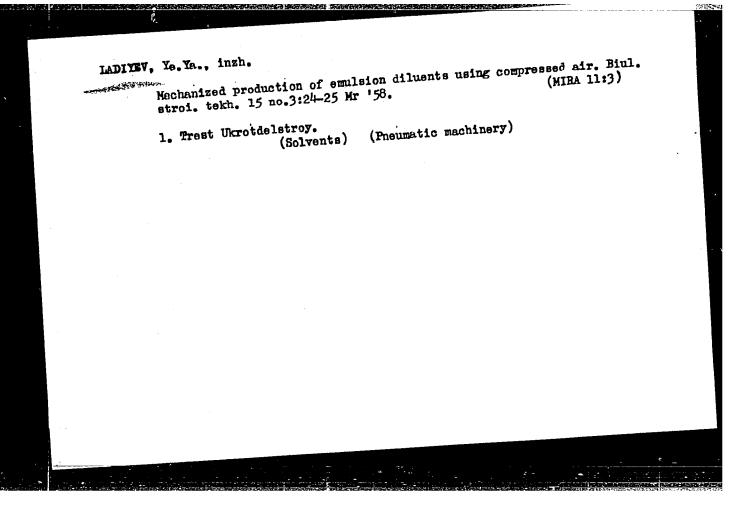
Machinery for finishing operations. Biul.stroi.tekh.14 no.7:13-15

Machinery for finishing operations. (MIRA 10:11)

J1 '57.

1. Trest Ukrotdelstroy.

(Painting, Industrial--Equipment and supplies)



LADIYEV, Ye.Ya., inzhener-mekhanik

The L-10-6 container for feeding putty mixes. Suggested by E.IA. Ladiev. Rats.i izobr.predl. v stroi. no.10:49-50 159.

1. Po materialam Tekhnicheskogo upravleniya Ministerstva stroitel stva USSR. (Putty)

CIA-RDP86-00513R000928420001-5" APPROVED FOR RELEASE: 06/19/2000

LADIYEVA, VILLTORIYA DANILOVNA

SEMENENKO, Nikolay Panteleymonovich; POLOVKO, Nataliya Ivanovna;

ZHUKOV, Georgiy Viktorovich; LADIYEVA, Viktoriya Danilovna;

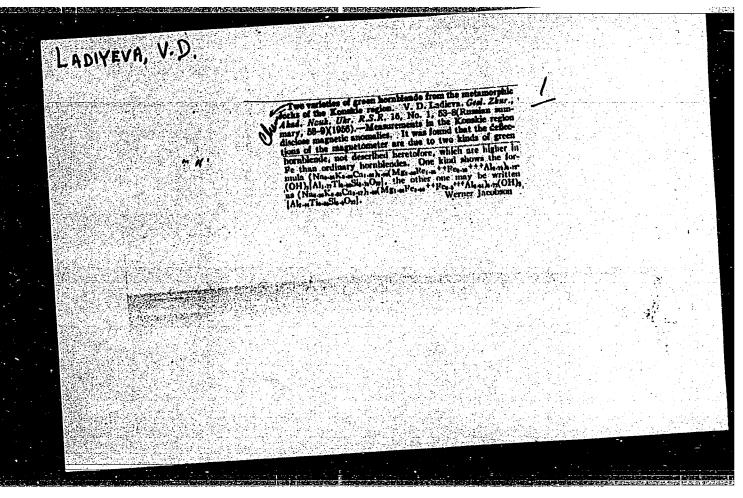
MAKUKHINA, Anna Aleksandrovna; ZAVIRYUKHINA, V.N., redaktor

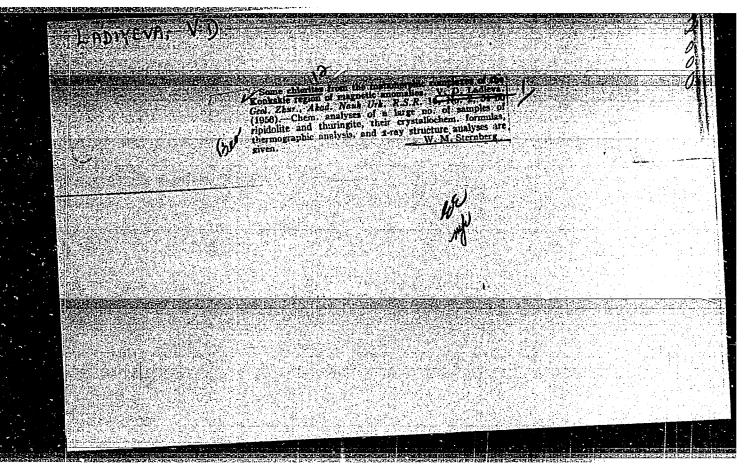
izdatelistva; RODIONOV, S.P., otvetstvennyy redaktor; ROZENTSVEYG,

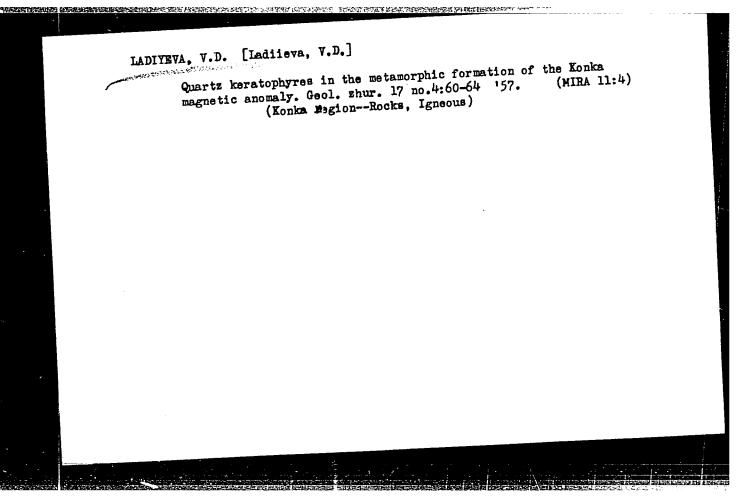
Ye.N., tekhredaktor

[Petrography of ferrosilicate formations of the Ukraine]
Petrografiia zhelezistokremnistykh formatsii Ukrainskoi SSR. Kiev.
Izd-vo Akad. nauk USSR, 1956. 535 p. (MLRA 10:4)

1. Chlen-korrespondent AN USSR. (for Rodionov)
(Ukraine--Petrology)







LADIYEVA, V.D.

SOV/2248 PHASE I DOOK EXPLOITATION

- 3(5) Semenenko, Nikolay Panteleymonovich, Nataliya Ivanovna Polovko, Yakov Mikhaylovich Gritskov, Mikhail Nikolayevich Dobrokhotov, Anna Aleksandrovna Makukhina, Viktoriya Danilovna Ladiyeva, Georgiy Viktorovich Zhukov, and Andrey Andreyevich Nastenko.
  - Geologiya zhelezisto kremnistykh formatsiy Ukrainy (Geology of Ferruginous-Silicified Formations of the Ukraine) Kiyev, Izdvo AN USSR, 1959. 687 p. Errata slip inserted. 2,000 copies printed.
  - Institut geo-Sponsoring Agency: Akademiya nauk Ukrainskoy SSR. logicheskikh nauk.
  - Eds: S.P. Rodionov, Corresponding Member, USSR Academy of Sciences; Ed. of Publishing House: V.N. Zaviryukhina; Tech. Ed.: Ye. N. Rozentsveyg.
  - PURPOSE: This book is intended for industrial and research geologists, teachers and advanced students of geology.

Card 1/29

CIA-RDP86-00513R000928420001-5" APPROVED FOR RELEASE: 06/19/2000

,但是是一个人,也是是一个人的人,也是是一个人的人,也是是一个人的人,也是是一个人的人的人,也是是一个人的人的人,也可以是一个人的人,也是一个人的人。

IADIYEVA, V.D. [Ladiieva, V.D.]

Mineralogy of ultrabasites of the Belozerskiy region.

MIRA 14:6)
Dop.AN URSR no.6:801-805 161.

1. Institut geologicheskikh nauk AN USSR. Predstavleno akademikom AN USSR N.P. Semenenko [Semenenko, M.P] (Zaporozh ye Province—Rocks, Igneous)

BELEVISEV, Ya.N.; FOMENKO, V.Yu.; NOTAROV, V.D.; MOLYAVKO,G.I.; MEL'NIK, Yu.P.; SIROSHTAN, R.I.; DOVGAN', M.N.; CHERNOVSKIY, M.I.; SHCHERBAKOVA, K.F.; ZAGORUYKO, L.G.; GOROSHNIKOV, B.I.; AKIMENKO, N.M.; SEMERGEYEVA, Ye.A.; KUCRER, V.N.; TAKHTUYEV, G.V.; KALYAYEV, G.I.; ZARUBA, V.M.; NAZAROV, P.P.; MAKSIMOVÍCH, V.L.; STRUYEVA, G.M.; KARSHENBAUM, A.P.; SKARZHINSKAYA, T.A.; CHEREDNICHENKO, A.I.; GERSHOYG, Yu.G.; PITADE, A.A.; RADUTSKAYA, P.D.; ZHILKINSKIY, S.I.; KAZAK, V.M.; KACHAN, V.G.; STRYGIN, A.I., red.; LADIYEVA, V.D., red.; ZHUKOV, G.V., red.; YEPATKO, Yu.M., red.; SHCHERBAKOV, B.D., red.; SLENZAK, O.I., red.izd-va; RAKHLINA, N.P., tekhn. red. [Geology of Krivoy Rog iron-ore deposits]Geologiia Krivorozhskikh zhelezorudnykh mestorozhdenii. Kiev, Izd-vo Akad. nauk USSR. Vol.1. [General problems in the geology of the Krivoy Rog Basin. Geology and iron ores of the deposits of the "Ingulets," Rakhmanovo, and Il'ich Mines]Obshchie voprosy geologii Krivbassa. Geologicheskoe stroenie i zheleznye rudy mestorozhdenii rudnikov "Ingulets," Rakhmanovskogo i im, Il'icha. 1962. 479 p. (MIRA 16:3) (Krivoy Rog Basin-Mining geology) (Krivoy Rog Basin--Iron ores)

### LADIYEVA, V.D.

Ultrabasites of siliceous-iron formations in the Ukrainian Crystalline Shield and associated asbestos and talc-magnesium deposits. Zakonom. razm. polezm. iskop. 6:61-75 '62. (MIRA 16:6)

1. Institut geologicheskikh nauk AN UkrSSR.

(Dnieper Valley-Ultrabasite)

(Dnieper Valley-Talc)

(Dnieper Valley-Magnesium)

(Dnieper Valley-Asbestos)

BELEVTSEV, Ya.N.; FOMENKO, V.Yu.; NOTAROV, V.D.; MOLYAVKO, G.I.;

MEL'NIK, Yu.P.; SIROSHTAN, R.I.; DOVGAN', M.N.; CHERNOVSKIY,

M.I.; SHCHERBAKOVA, K.F.; ZAGORUYKO, L.G.; GOROSHNIKOV, B.I.;

AKIMENKO, N.M.; SEMERGEYEVA, Ye.A.; KUCHER, V.N.; TAKHTUYEV, G.V.;

KALYAYEV, G.I.; ZARUBA, V.M.; NAZAROV, P.P.; MAKSIMOVICH, V.L.;

STRUYEVA, G.M.; KARSHENBAUM, A.P.; SKARZHINSKAYA, T.A.;

CHEREDNICHENKO, A.I.; GERSHOYG, Yu.G.; PITADE, A.A.; RADUTSKAYA,

P.D.; ZHILKINSKIY, S.I.; KAZAK, V.M.; KACHAN, V.G.; POLOVKO,N.I.,

red.; LADIYEVA, V.D., red.; ZHUKOV, G.V., red.; YEPATKO, Yu.M.,

red.; SLENZAK,O.I., red. izd-va; KULICHENKO, V.G., red.;

RAKHLINA, N.P., tekhn. red.; MATVEYCHUK, A.A., tekhn. red.

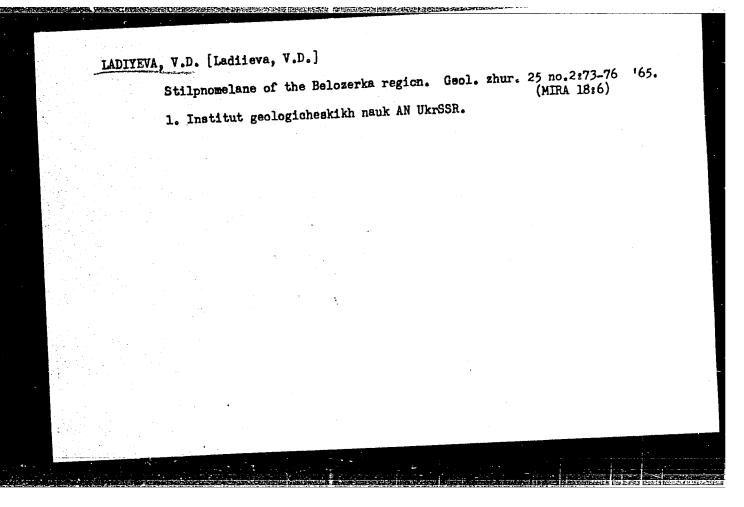
[Geology of the Krivoy Rog iron ore deposits] Geologiia Krivorozhskikh zhelezorudnykh mestorozhdenii. Kiev, Izd-vo Akad. nauk
USSR. Vol.1.[General problems of the geology of the Krivoy Rog
Basin. Geology and iron ores of the "Ingulats," Rakhmanovskiy,
Basin. Geology and iron ores of the "Ingulats," Rakhmanovskiy,
and Il'ich ore deposits] Obshchie voprosy geologii Krivbassa.
and Il'ich ore deposits] Obshchie voprosy geologii Krivbassa.
Geologicheskoe stroenie i zheleznye rudy mestorozhdenii rudnikov
Geologicheskoe stroenie i ins. Il'icha. 1962. 479 p. Vol.2.[Ge"Ingulets," Rakhmanovskogo i im. Il'icha. 1962. 479 p. Vol.2.[Ge"Ingulets," Rakhmanovsko

SEMENENKO, N.P.: SUBBOTIN, C. .. SOLLOGUB, V.B.: IVANTISHIN, M.N.; CHFKUNOV, A.V.; LADIYEVA V.F.

Structure of the abyssal zones of the earth's crust in the Ukrainian Crystalline Shield. Sov. geol. 7 no.11:48-60 N '64.

(MTRA 18:2)

1. Institut geofiziki AN UkrSSR.



LADIYEVA, V.D. [Ladieva, V.D.]

Katarcheen volcanic sedimentary formations in the Konka-Belozerka
Zone. Geol. zhur. 22 no.1:35-48 164.

1. Institut geologicheskikh nauk AN UkrSSR.

PASTERNAK, Severin Ivanovich; Ladizhenskiy, M.R. [Ledyzhene'kyi, M.R.],
doktor geol.-mineral.nauk, otv.red.; OVCHAROVA, Z.G.[Ovcharova,
Z.H.], red.; BUHIY, R.O., tekhn.red.

[Biostratigraphy of Cretaceous deposits of the Volyn'-Podolian
Upland] Biostratygrafiia kreidovykh vidkladiv Volyno-Podil's'koi
upland] Biostratygrafiia kreidovykh vidkladiv Volyno-Podil's'koi
upland] Kyiv, Vyd-vo Akad.nauk URSR, 1959. 98 p. (MIRA 13:4)
(Volyn'-Podolian Upland--Paleontology, Stratigraphic)

FEDUSHCHAK, Mikhail Yur'yevich; LADIZHENSKIY, M.R. [Ladyzhens'kyi, M.R.], prof., otv. red.; MEL'NIK, G.F. [Mel'nyk, H.F.], red. izd-va; DAKHNO, Yu.B., tekhn. red.

[Formation of exotic conglomerates in the Vorotyshcha series of the cis-Carpathian region]Umovy utvoremnia ekzotychnykh konglomerativ vorotyshchens'koi serii Peredkarpattia. Kyiv, konglomerate vorotyshchens'koi serii Peredkarpattia. Kyiv, Vyd-vo Akad. nauk URSR, 1962. 110 p.

(MIRA 16:1)

(Carpathian Mountain region—Conglomerate)

LADKIN., V. YE.

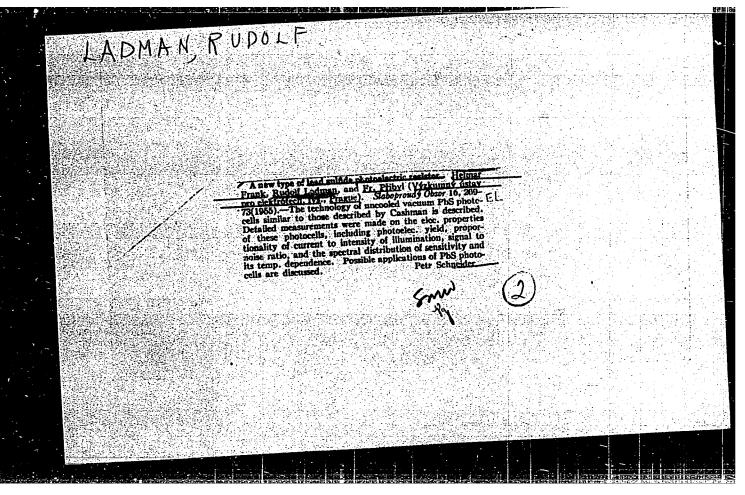
USSR/Medicine - Spirochetosis
 Medicine - Epidemiology

"A Case of Leptospirosis in the Crimea, " K. D. Pyatkin, V. Ye. Laskin, E. H. Sultanakaya,
L. Ts. Besprozvannaya, 2 pp

"Gigiyena i Sanitariya" Vol XII, No 5

DEtailed discussion giving epidemiological data. Concludes, among other things, that the
most probable sources of water fever are rats and horned cattle.

PA 16743



H-13

LADMAN, RUDOLF

CZECHOSLOVAKIA/Chemical Technology. Chemical Products and Their

Application, Ceramics. Glass. Bixcers. Concrete.

Abs Jour: Referat Zhur-Khimiya, No 5, 1958, 15288.

Ladman Rudolf, Reichel Theofil. Author :

Inst : Transparent Conductive Layers on Class. Title

Orig Pub: Slaboproudy obzor, 1957, 18, No 4, 194-197

Abstract: A review of the different methods of costing glass with

transparent conductive layers. Particular attention is

given to the so-called oxide layers.

: 1/1 Card

CIA-RDP86-00513R000928420001-5" APPROVED FOR RELEASE: 06/19/2000

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9,4140

z/037/60/000/005/036/056

Holý, B. and Ladman, R. E192/E382

**AUTHORS:** 

TITLE:

The Problem of Background in a Quanticon

PERIODICAL:

Československý časopis pro fysiku, 1960

No. 5, p. 434

The parasitic signals caused by the difference between the axial energy of the electrons in the beam and the influence of the instability of the potential fall of the storage electrode (as a source of interference signals) were investigated. The distortion of the picture observed at high intensities of the electron beam is investigated. The influence of the technological processes on the "background" is also analysed.

ASSOCIATION:

Výzkumný ústav pro vakuovou elektrotechniku,

Praha (Research Institute for Vacuum

Electrotechnology, Prague)

Card 1/1

HOLY, Bohumil, inz.; LADMAN, Rudolf, inz.

Problem of the background in vidicon tubes. Shor wak elektrotech 3:24-35 161.

1. Vyzkumny ustav pro vakuovou elektrotechniku, Praha.

CIA-RDP86-00513R000928420001-5" APPROVED FOR RELEASE: 06/19/2000

#### "APPROVED FOR RELEASE: 06/19/2000 CIA-RDP86-00513R000928420001-5 医医院检验 医性性性性 医动物 计记录计划 医多种性 医皮肤 经工程 医皮肤

LADMAR H.

CZECHOSLOVAKIA/Electricity - Semiconductors.

G

Abs Jour

: Ref Zhur Fizika, No 4, 1960, 9087

Cerny Ladislav, Husa Vaclav, Kriz Josef, Ladmar Hosef proceedings of the process of the

Author Inst

Title

: The p-n Junction in Germanium

Orig Pub

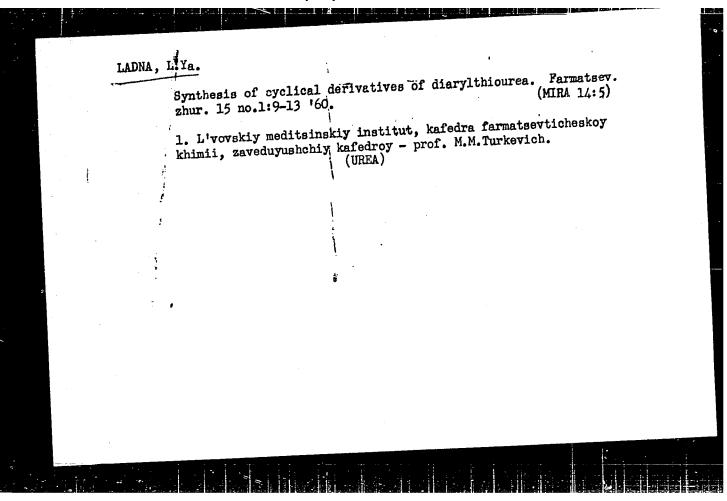
Electrotech. obzor, 1959, 48, No 8, 406-409

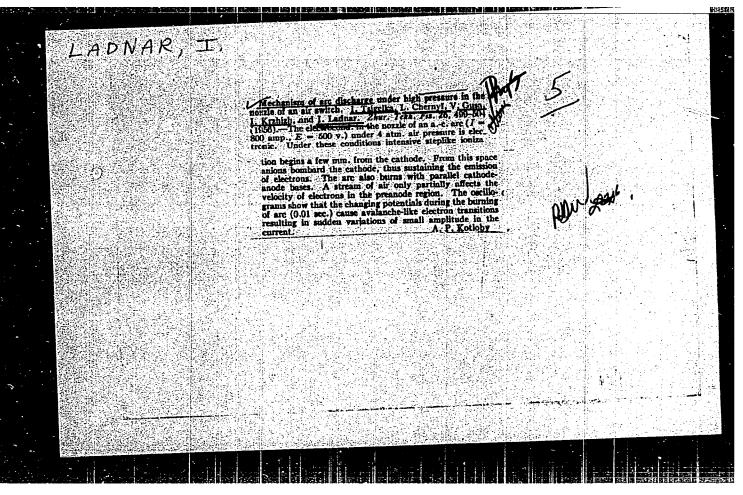
Abstract

: A brief description of the physical primciple of the p-n junction in germanium, and a comparison of the theoretical premises with the experimental data. Problems of technology are considered, and certain results of experimental investigation of the p-n junction are given. A technology is recommended, which insures small dispersion of the characteristic in the forward and backward

See Referat Zhur Fizika, 1960, No 3, 618.

Card 1/1

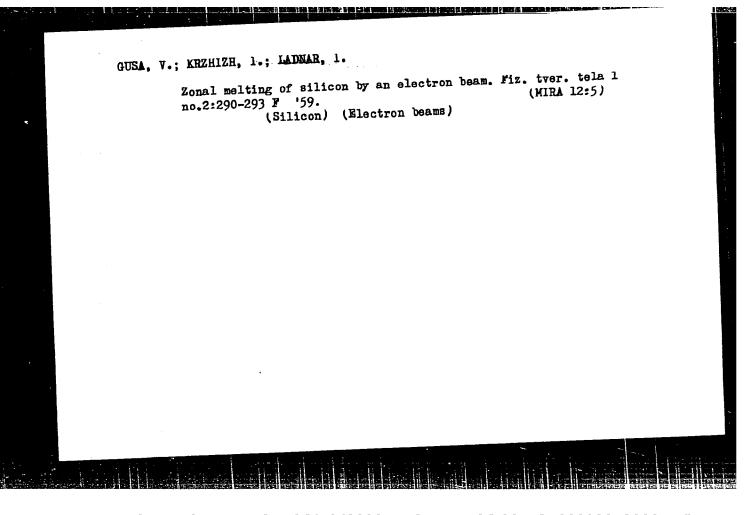




GUSA, V., doktor tekhnicheskikh nauk; KRZHIZH, I.; LADNAR, I.; CHERNYY, L., inzhener.

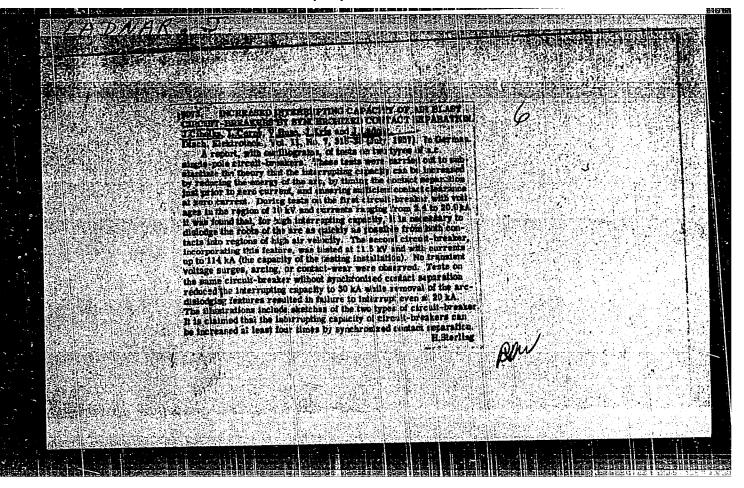
Drying compressed air for high-voltage circuit breakers. Elek.sta. (MLRA 9:6) 27 no.2:26-31 F 156.

l.Nauchno-issledovatel'skiy institut sil'notochnoy elektrotekhniki, Chekhoslovakiya. (Electric circuit breakers) (Drying apparatus)



Pz-5/P1-4 1. 53587-65 EWT(1)/EWT(m)/T/EWP(t)/SEC(b)-2/EWP(b)/EWA(b)/EWA(c) Z/0000/62/000/000/0120/0122 JD/30/AT AT5009576 ACCESSION NR: AUTHOR: Huse, V.; Gusa, V. (Kriz, J.), Ladner, J. (Krzhigh, I., Ladnar, I. Experience in producing single crystals and p-n transitions in Sic TITLE: Konference o monokrystalech. 4th, Turnov, 1961. Sbornik referatov. SOURCE: Turnov, VUM, 1962, 120-122 TOPIC TAGS: single crystal, semiconductor crystal, crystal growth, silicon carbide ARSTRACT: In 1960, the authors' Institute began work on the production of clear SIC single crystals as high-purity semiconductors with high activation energy, as well as p-n transitions in SiC. The activation energy of SiC is 2.86 ev. The crystals are either cubic, called \$\text{\$\text{\$P-SiC}\$ and obtained at 2000C or hexagonal c-I to crystals are either cubic, called \$\text{\$\text{\$P-SiC}\$ and obtained at 2000C or hexagonal c-I to called \$\text{\$\text{\$VI}\$, obtained at 2400-2600C. The latter are used in electrical equipment. The called \$\text{\$VI}\$, obtained at 2400-2600C. The latter are used in electrical equipment. It has institute built a small furnace to refine SiC by the method of A. H. Smith. It has two compartments, both water-copied, with a carbon heating element 180 mm long,
25 mm in external diameter and 20 mm in internal diameter, encased in a graphite insulating cylinder. Through the furnace floor passes an argon intake with an optical pyrometer to control the temperatures, while the argon outlet passes through the Card 1/2

LOD: A carbon pedestal in	the center of the heartwo	delement supports a nozzle and
current at 600 Ase and 3 1	sy input. Sic crystals for	leated to 2600C by alternating
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figures.	in cms and a 60 km current.	input. Orig. art. has: 5
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Research Institute for Hig	h-Voltage Equipment)	A COLUMN TO A COLU
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LADNAR, 5.	669.782/783; 621.514.63 1 615. NEW TECHNOLOGY FOR THE MANUFACTURE OF GERMANIUM POWER DIODES: 25 J. Chelka, L. Cerny, V. Husa, J. Krist and J. Ladnar, Blaboproudy Obzor, Vol. 19, No. 9, 589-52 (1958). In Czech, The new technique is based on the use of a special carbon jig	6	
	which is constructed in such a manner that all the technological operations involved in the making of a germanium diode, are completed by placing a fully assembled jig in the processing oven. The assembly of the jig is as follows. A molybdenam cup containing a piece of 0.1 mm tinfoil is placed on top of a copper huse plate which carries a sheet of 0.2 mm tinfoil; a germanium wafer is placed on top of the foil inside the cup; on top of the wafer comus a piece of 9.3 mm indium foil and a second Mo cup; this cup also contains a piece of finfoil having a thickness of 0.7 mm; a braided copper lead, terminated with a Fe end-piece, is placed into the top cup. The use of the jig permits the manufacture of 10 A diodes with a small spread.  Distre 4Eld		
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LADNAR, J.

CZECHOSLOVAKIA/Electronics - Photocells and Semiconductor Device. H

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Abs Jour

: Ref Zhur Fizika, No 1, 1960, 1551

Author

: Husa, V., Kriz, J., Ladnar, J.

Inst

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Title

: p\* -- p -- n\* Junctions in Silicon

Orig Pub

: Slaboproudy obzor, 1959, 20, No 5, 284-287

Abstract

: The author considers the physical basis of the p\* -- i -- n\* junction and justifies the choice p\* -- p -- n\* junction for use in a silicon diode. The technology of manufacture of diodes with large junction surface and with reverse voltage greater than 1,000 volts is considered. Conditions are determined for obtaining sufficiently small resistance in the forward direction.

Card 1/1

s/194/62/000/004/076/105 D295/D308

AUTHORS:

Cihelka, Jaroslav, Cerný, Ladislav, Husa, Václav, Kříž, Josef and Ladnar, Josef

TITLE:

Device for the stabilization of the operation of semiconductor-rectifier sections connected in parallel

PERIODICAL:

Referativnyy zhurnal, Avtomatika i radioelektronika, no. 4, 1962, abstract 4-5-56f (Czechosl. pat., cl. no. 4, 12/02; 21g, 11/02; 21d3, 2, no. 97375, 15.11.60) 21d2, 12/02; 21g, 11/02; 21d3

TEXT: The principle of the distribution of the cooling medium in rectifiers with parallel-connected semiconductor diodes is cutlined. When diodes are connected in series or in parallel, the pronea. when aloaes are connected in series or in parallel, the pro-blem of temperature stability is especially difficult, since it is impossible in practice to choose diodes having exactly the same impossible in practice to choose diodes having exactly the same characteristics and, in particular, the same temperature dependence on the current-voltage characteristic, which would enable us to use for them a common equipment for cooling or temperature regulature for them accommon equipment for cooling or temperature.

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**39617** S/194/62/000/004/047/105 D201/D308

Husa, Václav, Kříž, Josef and Ladnar, Josef

AUTHOR:

A silicon diode

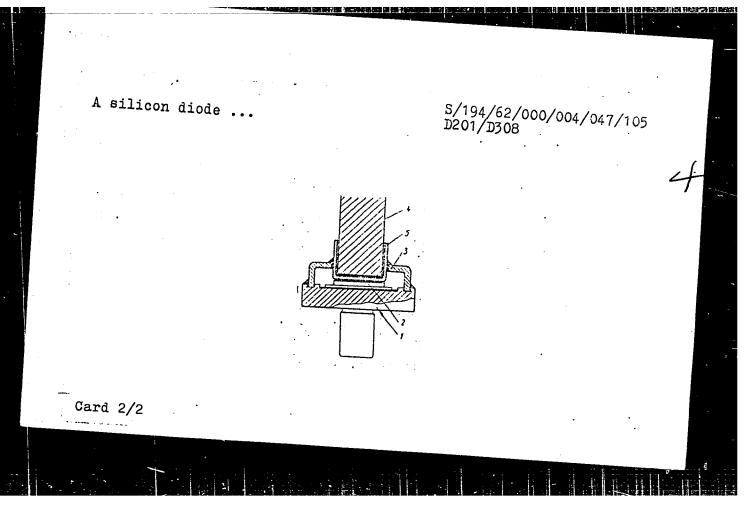
PERIODICAL: Referativnyy zhurnal, Avtomatika i radioelektronika, no. 4, 1962, abstract 4-4-46v (Czechosl. pat., cl.

21g, 11/02, no. 97461, 15.11.60)

TEXT: The author proposes a construction of diodes, in which the whisker contact, making the hermetic sealing of the diode difficult, is dispensed with. In the usual systems the whisker is incult, is dispensed with. side the space to be scaled off. In the given constructions (see Fig.) the hermetic ceramic cartridge 3 contains only the silicon rectifying element 2. The bottom of the cartridge is formed by a copper plate 1 which acts as the lower contact to the rectifier and the upper section consists of a metal cylinder 5, the bottom of which is used as the second contact; external lead 4 is inserted in the upper cylinder. / Abstracter's note: Complete translation. 7

Card 1/2

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**39618** S/194/62/000/004/049/105 D201/D308

1,4340

AUTHORS: Husa, Václav, Kříž, Josef and Ladnar, Josef

TITLE: A method of manufacturing silicon semiconductor diodes

PERIODICAL: Referativnyy zhurnal, Avtomatika i radioelektronika, no. 4, 1962, abstract 4-4-47v (Czechosl. pat., cl.

21g, 11/02, no. 97215, 15.11.60)

TEXT: A method of manufacturing powerful alloyed silicon semiconductor diodes is proposed. The method is distinguished in that an etching agent is deposited at the area of contact between the alloyed golden contact and the silicon wafer. The etching agent consists of a mixture of 1 part of concentrated HNO3 and 3 parts of

concentrated HCl. After washing with distilled water, the diode manufacturing process may follow the usual technological procedure. The new method makes it possible to improve considerably the electric properties of the semiconductor diode without appreciable increase in the cost of its manufacture. Abstracter's note: Complete translation.

38197 s/058/62/000/004/160/160 A061/A101

AUTHORS:

Husa, V., Kříž, J., Ladnar, J.

Production technique for silicon semiconductor diodes

PERIODICAL: Referativnyy zhurnal, Fizika, no. 4, 1962, 24, abstract 4-4-47v P

(Chekhosl. pat. kl. 21 g, 11/02, no. 97215, 15.11.60)

The production technique suggested for silicon alloys designed for semiconductor power diodes is characterized by the fact that the pickling agent, consisting of 1 part of concentrated HNO3 and 3 parts of concentrated HCl, is applied to the contact surface of a fused-in gold electrode and a silicon plate. After washing with distilled water, the completion of manufacturing semiconductor diodes is continued with the conventional technical processes. By the new method, the electrical properties of semiconductor diodes are improved significantly without any substantial increase of manufacturing costs.

A. S.

[Abstracter's note: Complete translation]

Card 1/1

CIA-RDP86-00513R000928420001-5" **APPROVED FOR RELEASE: 06/19/2000** 

HUSA, Vaclav, inz., dr.; LADNAR, Josef

Diffusion computation profiles of flat transistors. Slaboproudy obzor 23 no.2:119-120 F '62.

HUSA, Vaclav, inz. dr., kandidat technickych ved; KRIZ, Josef; LUXA, Frantisek

Contribution to the technology of the silicon Mesa power transistor. El tech obzor 52 no.10:538-540 0 163.

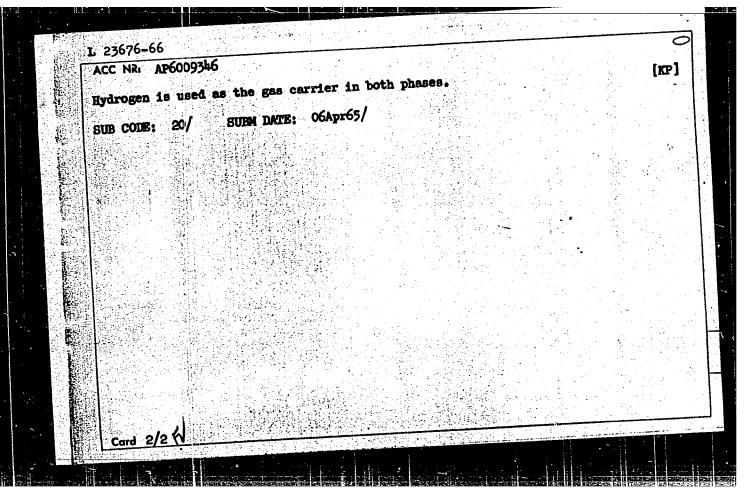
1. Statni vyzkumny ustav silnoproude elektrotechniky.

ACC NR: AP6006150 (A) SOURCE CODE: CZ/0078/65/000/010/0010/0010 AUTHOR: Huss, Vaclav (Dr., engineer, Doctor of Sciences) (Pecky); Bydzovsky, J. (Engineer) (Sadska); Kriz, J. (Prague); ORG: None TITLE: (Overvoltage protection device for rectifying semiconductor diode) SOURCE: Vynalezy, no. 10, 1965, 10 TOPIC TAGS: semiconductor device, semiconductor diode, Zener diode, zener effect ABSTRACT: A device is described for protecting a rectifying semiconductor diode, or a group of several parallel or series-parallel connected diodes from overvoltage, and is distinguished by the feature that to the diode of group of diodes is connected a parallel matched polarized breakdown (Zener) diode, or a group of several breakdown diodes connected in series, in parallel or in series-parallel. The Zener voltage on the breakdown diode in the reverse (non-conducting) direction, or the value of the sum of the Zener voltages in the reverse direction in the breakdown diodes connected in series is lower than the breakdown voltage of the diode to be

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	ACC NR: AP6009340  AUTHOR: Husa, Vaclay (Engineering, Doctor of Sciences,  AUTHOR: Husa, Vaclay (Engineering, Doctor of Sciences,  Ladnar, Tosef (Prague); Luxa, Frantisek (Horni Pocernice)  Ladnar, Tosef (Prague); Pate No. PV 1792-63
	ORG: none
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2	SOURCE: Vynalezy, no. 11, 1907,  SOURCE: Vynalezy, no. 11, 1907,  TOPIC TAGS: silicon element, collector emitter, gallium compouncy,  TOPIC TAGS: silicon element, collector emitter, gallium compouncy,  The element of a.  The element  ABSTRACT: An Author Certificate has been issued for a method of manufacture of a.  The element  ABSTRACT: An Author Certificate has been issued for a method of manufacture of a.  The element  ABSTRACT: An Author Certificate has been issued for a method of manufacture of a.  The element  ABSTRACT: An Author Certificate has been issued for a method of manufacture of a.  The element  ABSTRACT: An Author Certificate has been issued for a method of manufacture of a.  The element  ABSTRACT: An Author Certificate has been issued for a method of manufacture of a.  The element  ABSTRACT: An Author Certificate has been issued for a method of manufacture of a.  The element  ABSTRACT: An Author Certificate has been issued for a method of manufacture of a.  The element  ABSTRACT: An Author Certificate has been issued for a method of manufacture of a.  ABSTRACT: An Author Certificate has been issued for a method of manufacture of a.  The element  ABSTRACT: An Author Certificate has been issued for a method of manufacture of a.  ABSTRACT: An Author Certificate has been issued for a method of lower conducture.  ABSTRACT: An Author Certificate has been issued for a method of lower conducture.  ABSTRACT: An Author Certificate has been issued for a method of lower conducture.  ABSTRACT: An Author Certificate has been issued for a method of lower conducture.  ABSTRACT: An Author Certificate has been issued for a method of lower conducture.  ABSTRACT: An Author Certificate has been issued for a method of lower conducture.  ABSTRACT: An Author Certificate has been issued for a method of lower conducture.  ABSTRACT: An Author Certificate has been issued for a method of lower conducture.  ABSTRACT: An Author Certificate has been issued for a method of lower conducture.  ABSTRACT: An Author Certificate has
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SOURCE CODE: CZ/0078/66/000/009/0019/0020 AUTHOR: Novotny, Vladimir (Engineer; Tabor); Husa, Vaclav (Doctor; Engineer; ACC NR: AP6035301 Doctor of sciences; Pecky); Kriz, Josef (Prague); Bydzovsky, Jan (Engineer; Zasmukh); Ladnar, Josef (Prague); Luxa, Frantisek (Horni Pocernice) TITLE: Ignition equipment for jet and turbojet engines. CZ Pat. No. PV 1920-65 ORG: none SOURCE: Vynalezy, no. 9, 1966, 19-20 TOPIC TAGS: power plant component, fuel igniter, engine ignition system, jet engine, jet engine component, turboprop engine, turboprop engine component, ABSTRACT: Ignition equipment, especially for use with aircraft jet and turboprop spark plug, low voltage spark plug engines, is introduced. It has a low-voltage spark plug and is fed by d-c supply. The secondary winding of the induction coil is connected through the rectifier to the capacitor. The sparking circuit is connected in parallel to the capacitor and connected in series with the low-voltage spark plug. One end of the primary winding of the induction coil is connected to the first pole of the d-c supply. The other end Card 1/2

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transistor a to the other	nd the outlet of the pole of the d-c su le of the d-c suppl	e emitter of the opply and another	which is conne	ected
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